

Total No. of Questions : 8]

SEAT No. :

P2075

[Total No. of Pages : 2

[4460] - 735

M.E. (E&T/C) (VLSI & Embedded Systems) (Semester - I)

DIGITAL CMOS DESIGN

(2013 Pattern)

Time : 3 Hours]

[Max. Marks :50

Instructions to the candidates:

- 1) *Answer any five questions.*
- 2) *Neat diagrams must be drawn wherever necessary.*
- 3) *Use of electronic pocket calculator is allowed.*
- 4) *Assume suitable data, if necessary.*

- Q1)** a) Draw ac equivalent ckt of MOSFET & explain parasitics in detail. [5]
b) What is λ parameter? List layout design rules. Draw layout of CMOS Inverter. [5]
- Q2)** a) Explore CMOS fabrication steps in detail. [5]
b) What is technology scaling? Explain in brief. [5]
- Q3)** a) Derive the expression for dynamic power dissipation. [4]
b) Pertaining to CMOS logic, explain Fan in and Fan out. Explain dependencies analytically. [4]
c) Why is MOSFET sizing necessary? What are the effects if sizing is not followed? [2]
- Q4)** a) What is significance of Power Delay Product? Derive the expression.[4]
b) Explore delay model in brief. [4]
c) Give the expression for static dissipation of certain logic. Compare it with dynamic dissipation. [2]
- Q5)** a) Design CMOS logic for $X = ABCD + EF + G$. Calculate area on chip. [4]
b) What are the types of hazard? Explore any one with suitable example along with solutions. [4]
c) Explain limitations of Transmission Gate? What are the solutions? [2]

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- Q6)** a) Design 8:1 Mux using Transmission Gates. Compare with the conventional method. [4]
b) What is metastability? Explain the solution in detail. [4]
c) What is importance of tristate logic? Draw CMOS tristate logic. [2]
- Q7)** a) Explain the techniques for low power design. [4]
b) What is ratioed ckt? Explain with example. [4]
c) Compare logic ckt families. [2]
- Q8)** a) With the help of schematic example, explain sense amplifier ckt. [4]
b) What is need of BiCMOS ckt? Explore with appropriate logic ckt. [4]
c) Write note on static CMOS. [2]

